
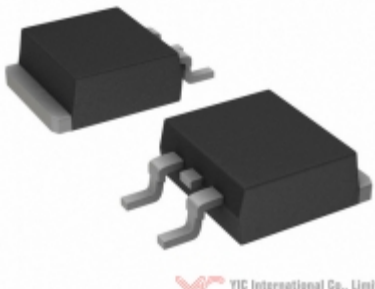


 	<h2 style="color: red;">FQB3P50TM</h2> <p>Hersteller-Teilenummer: FQB3P50TM</p> <p>Hersteller / Marke: Fairchild/ON Semiconductor</p> <p>Teil der Beschreibung: MOSFET P-CH 500V 2.7A D2PAK</p> <p>Datenblätter:  FQB3P50TM.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 2700 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	FQB3P50TM
Hersteller	Fairchild/ON Semiconductor
Beschreibung	MOSFET P-CH 500V 2.7A D2PAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	2700 pcs Stock
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-263-3, D ² Pak (2 Leads + Tab), TO-263AB
Supplier Device-Gehäuse	D ² PAK (TO-263AB)
Verlustleistung (max)	3.13W (Ta), 85W (Tc)
Typ FET	P-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	500V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	2.7A (Tc)
Rds On (Max) @ Id, Vgs	4.9 Ohm @ 1.35A, 10V
VGS (th) (Max) @ Id	5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	23nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	660pF @ 25V
Verpackung	Tape & Reel (TR)


















FQB3P50TM ist neu im Original, Suche FQB3P50TM Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQB3P50TM Fairchild/ON Semiconductor mit Garantie und Vertrauen. Anfrage FQB3P50TM: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>FQB3P20TM Fairchild/ON Semiconductor MOSFET P-CH 200V 2.8A D2PAK</p>	 <p>FQB3P20 FSC FQB3P20 FSC</p>	 <p>FQB44N10TM AMI Semiconductor / ON Semiconductor MOSFET N-CH 100V 43.5A D2PAK</p>	 <p>FQB3P50TM AMI Semiconductor / ON Semiconductor MOSFET P-CH 500V 2.7A D2PAK</p>
 <p>FQB44N10 Fairchild FQB44N10 Fairchild</p>	 <p>FQB44N10TM Fairchild/ON Semiconductor MOSFET N-CH 100V 43.5A D2PAK</p>	 <p>FQB3N90TM AMI Semiconductor / ON Semiconductor MOSFET N-CH 900V 3.6A D2PAK</p>	 <p>FQB3N90TM Fairchild/ON Semiconductor MOSFET N-CH 900V 3.6A D2PAK</p>

heiße Teile

Mehr

 FQB33N10TM	 FQB34N20	 FQB34N20L	 FQB34N20LTM	 FQB34N20LTM
 FQB34N20TM	 FQB34N20TM_AM002	 FQB34P10	 FQB34P10TM	 FQB34P10TM
 FQB34P10TM_F085	 FQB3N25TM	 FQB3N25TM	 FQB3N30TM	 FQB3N30TM
 FQB3N40TM	 FQB3N40TM	 FQB3N60C	 FQB3N80TM	 FQB3N80TM
 FQB3N90TM	 FQB3N90TM	 FQB3P20TM	 FQB3P20TM	 FQB3P50TM
 FQB44N10	 FQB44N10TM	 FQB44N10TM	 FQB46N15	 FQB46N15TM
 FQB47P06	 FQB47P06TM	 FQB4N20L	 FQB4N20LTM	 FQB4N20LTM
 FQB4N20TM	 FQB4N20TM	 FQB4N25TM	 FQB4N25TM	 FQB4N20TM
 FQB4N50TM	 FQB4N50TM	 FQB4N60C	 FQB4N80TM	 FQB4N80TM
 FQB4N90TM	 FQB4N90TM	 FQB4P25TM	 FQB4P25TM	 FQB50N03

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